NSN 5961-01-076-5818

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Inclosure Material:

Plastic

Overall Length:

Between 0.765 inches and 0.835 inches

Overall Height:

Between 0.170 inches and 0.190 inches

Overall Width:

Between 0.360 inches and 0.400 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

250.0 collector to emitter voltage/static/base open and 300.0 collector to emitter voltage, dc with base short-circuited to emitter and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 0.10 amperes source cutoff current and 0.10 amperes source cutoff current

Power Rating Per Characteristic:

9.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0

